

1.23.03

PATENT: Moore

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the application of:) Francisco I ania Wai Sina
Jen-Inn Chyi	Examiner: Louie, Wai Sing)
A 11 -1 N 10/030 100) Group Art Unit: 2814
Application No: 10/039,199) Date: January 13, 2003
Filed: January 4, 2002	TECH RI
For: BUFFER LAYER OF LIGHT EMITTING SEMICONDUCTOR DEVICE	Jan 2
AND METHOD OF FABRICATING THE	7
SAME	ZIII3
	Date: January 13, 2003 TECHNOLOGY CENTER 2800 CERTIFICATE OF MAILING
	I hereby certify that this correspondence is being deposited with the United States Postal Service as First Class Mail in an envelope

RESPONSE TO RESTRICTION REQUIREMENT AND AMENDMENT

January 13, 2003.

addressed to: Commissioner for Patents, Washington, DC 20231 on

Commissioner for Patents Washington, DC 20231

Dear Sir:

In response to the Restriction Requirement dated <u>December 11, 2002</u>, Applicant hereby elects, without traverse, group II, claims 11-20 and 21-23 to prosecute in the above-identified patent application.

IN THE CLAIMS

Please amend the claims as follows:

Please cancel claims 1-10 and 24-32, without prejudice.

- 14. (Amended) The method as claimed in claim 13, wherein said metallic nitride layer is an InN layer.
- 15. (Amended) The method as claimed in claim 11, wherein said metal layer is an aluminum layer.
 - 16. (Amended) The method as claimed in claim 15, wherein said metallic nitride

Attorney Docket No: JLINP055

